TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VHC175F,TC74VHC175FN,TC74VHC175FT,TC74VHC175FK

Quad D-Type Flip Flop with Clear

The TC74VHC175 is an advanced high speed CMOS QUAD D-TYPE FLIP FLOP fabricated with silicon gate C^2MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

These four flip-flops are controlled by a clock input (CK) and a clear input ($\overline{\rm CLR}$).

The information data applied to the D inputs (D1 thru D4) are transferred to the outputs (Q1 thru Q4 and $\overline{\,Q}1$ thru $\overline{\,Q}4$) on the positive-going edge of the clock pulse.

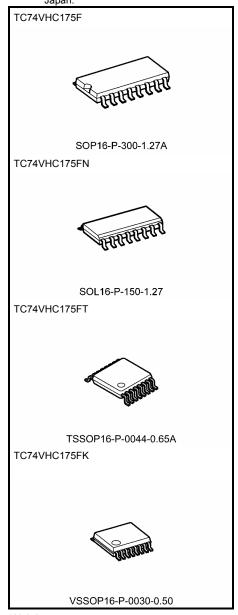
When the \overline{CLR} input is held low, the Q outputs are at the low logic level and the \overline{Q} outputs are at the high logic level, regardless of other input conditions.

An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

- High speed: $f_{max} = 210 \text{ MHz}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max)}$ at $T_a = 25 \text{°C}$
- High noise immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: $V_{CC \text{ (opr)}} = 2 \text{ to } 5.5 \text{ V}$
- Low noise: VOLP = 0.8 V (max)
- Pin and function compatible with 74ALS175

Note: xxxFN (JEDEC SOP) is not available in Japan.



Weight

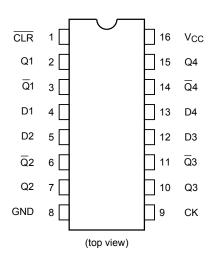
 SOP16-P-300-1.27A
 : 0.18 g (typ.)

 SOL16-P-150-1.27
 : 0.13 g (typ.)

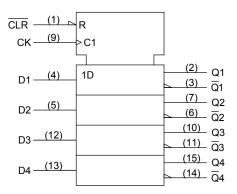
 TSSOP16-P-0044-0.65A
 : 0.06 g (typ.)

 VSSOP16-P-0030-0.50
 : 0.02 g (typ.)

Pin Assignment



IEC Logic Symbol

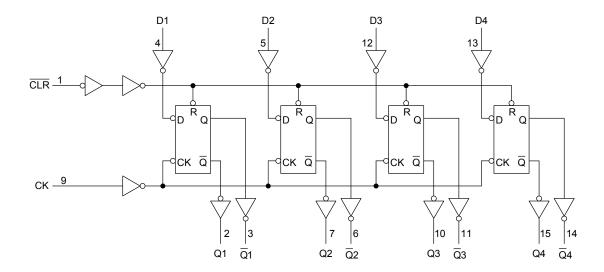


Truth Table

	Inputs		Out	puts	Function	
CLR	D	CK	Q	Q	Function	
L	Х	Х	L	Н	Clear	
Н	L		L	Н	_	
Н	Н		Н	L	_	
Н	Х	\rightarrow	Qn	Qn	No Change	

X: Don't care

System Diagram





Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	−0.5 to 7.0	V
DC input voltage	V _{IN}	−0.5 to 7.0	٧
DC output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5	V
Input diode current	I _{IK}	-20	mA
Output diode current	lok	±20	mA
DC output current	lout	±25	mA
DC V _{CC} /ground current	Icc	±50	mA
Power dissipation	PD	180	mW
Storage temperature	T _{stg}	-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Operating Range (Note)

Characteristics	Symbol	Rating	Unit	
Supply voltage	V _{CC}	2.0 to 5.5	V	
Input voltage	V _{IN}	0 to 5.5	V	
Output voltage	V _{OUT}	0 to V _{CC}	V	
Operating temperature	T _{opr}	−40 to 85	°C	
Input rise and fall time	dt/dv	0 to 100 (V _{CC} = 3.3 ± 0.3 V)	ns/V	
input rise and rail time	uvuv	0 to 20 ($V_{CC} = 5 \pm 0.5 \text{ V}$)	115/V	

Note: The operating range must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.



Electrical Characteristics

DC Characteristics

Characteristics	Symbol				7	a = 25°0		Ta = −40 to 85°C		Unit
Ondradichidae	Cymbol			V _{CC} (V)	Min	Тур.	Max	Min	Max	
High-level input voltage	V _{IH}	_			1.50 V _{CC} × 0.7	1 1	_ _	1.50 V _{CC} × 0.7	1 1	٧
Low-level input voltage	VIL	_			_ _	_ _	0.50 V _{CC} × 0.3	_ _	0.50 V _{CC} × 0.3	V
High-level output voltage	V _{ОН}	VIN = VIH or VIL	I _{OH} = -50 μA I _{OH} = -4 mA	2.0 3.0 4.5 3.0	1.9 2.9 4.4 2.58	2.0 3.0 4.5	_ _ _ _	1.9 2.9 4.4 2.48	_ _ _ _	٧
			I _{OH} = -8 mA	4.5	3.94	_	_	3.80	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	2.0 3.0 4.5		0.0 0.0 0.0	0.1 0.1 0.1		0.1 0.1 0.1	V
			I _{OL} = 4 mA I _{OL} = 8 mA	3.0 4.5		1 1	0.36 0.36		0.44 0.44	
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	_	±0.1	_	±1.0	μA
Quiescent supply current	Icc	V _{IN} = V _C	C or GND	5.5	_	ı	4.0	_	40.0	μA

Timing Requirements (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition	Test Condition			Ta = -40 to 85°C	Unit
			V _{CC} (V)	Тур.	Limit	Limit	
Minimum pulse width	t _{w (L)}		3.3 ± 0.3	_	5.0	5.0	20
(CK)	t _{w (H)}	_	5.0 ± 0.5	_	5.0	5.0	ns
Minimum pulse width	4		3.3 ± 0.3	_	5.0	5.0	20
(CLR)	t _{w (L)}	_	5.0 ± 0.5	_	5.0	5.0	ns
Minimum set-up time	+		3.3 ± 0.3	_	5.0	5.0	ns
wiiniinum set-up time	t _s	_	5.0 ± 0.5	_	4.0	4.0	115
Minimum hold time	4.		3.3 ± 0.3	_	1.0	1.0	
Minimum noid time	t _h	_	5.0 ± 0.5	_	1.0	1.0	ns
Minimum removal time			3.3 ± 0.3	_	5.0	5.0	
(CLR)	trem	_	5.0 ± 0.5	_	5.0	5.0	ns



AC Characteristics (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Tes	Test Condition		Ta = 25°C			Ta = −40 to 85°C		Unit
	,		V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	
			3.3 ± 0.3	15	_	7.5	11.5	1.0	13.5	- ns
Propagation delay time	t _{pLH}			50	_	10.0	15.0	1.0	17.0	
(CK-Q, \overline{Q})	t_{pHL}	_	5.0 ± 0.5	15	_	4.8	7.3	1.0	8.5	
			5.0 ± 0.5	50	_	6.3	9.3	1.0	10.5	
			3.3 ± 0.3	15	_	6.3	10.1	1.0	12.0	
Propagation delay time $(\overline{\text{CLR}} - Q, \overline{Q})$	t _{pLH} t _{pHL}	_	3.3 ± 0.3	50	_	8.8	13.6	1.0	15.5	- ns
			5.0 ± 0.5	15	ı	4.3	6.4	1.0	7.5	
				50	_	5.8	8.4	1.0	9.5	
	f _{max}	-	3.3 ± 0.3	15	90	140	_	75	_	- MHz
Maximum clock				50	50	75	_	45	_	
frequency			5.0 ± 0.5	15	150	210	_	125	_	
				50	85	115	_	75	_	
Output to output skew	t _{osLH}	(Note 1)	3.3 ± 0.3	50	ı	_	1.5	_	1.5	ns
Output to output skew	t _{osHL}	(Note 1)	5.0 ± 0.5	50		_	1.0	_	1.0	113
Input capacitance	C _{IN}		_		ı	4	10	_	10	pF
Power dissipation capacitance	C _{PD}			(Note 2)	-	44	_	_	_	pF

Note 1: Parameter guaranteed by design.

 $t_{OSLH} = |t_{pLHm} - t_{pLHn}|, t_{OSHL} = |t_{pHLm} - t_{pHLn}|$

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4 (per bit)$$

And the total C_{PD} when n pcs.of flip flop operate can be gained by the following equation:

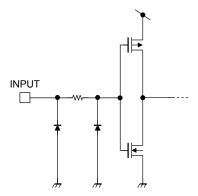
C_{PD} (total) = 30 + 14·n

Noise Characteristics (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	Ta=	Unit		
Gridiacteristics	Symbol		V _{CC} (V)	Тур.	Max	Oi ii
Quiet output maximum dynamic V _{OL}	V _{OLP}	C _L = 50 pF	5.0	0.4	8.0	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	C _L = 50 pF	5.0	-0.4	-0.8	V
Minimum high level dynamic input voltage	V_{IHD}	C _L = 50 pF	5.0	_	3.5	V
Maximum low level dynamic input voltage	V_{ILD}	C _L = 50 pF	5.0	_	1.5	٧



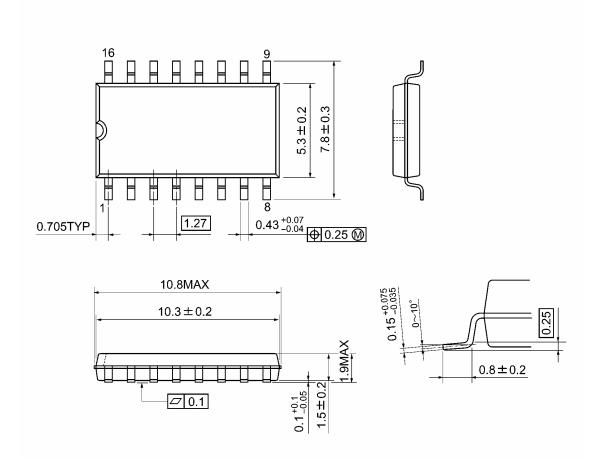
Input Equivalent Circuit



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Package Dimensions

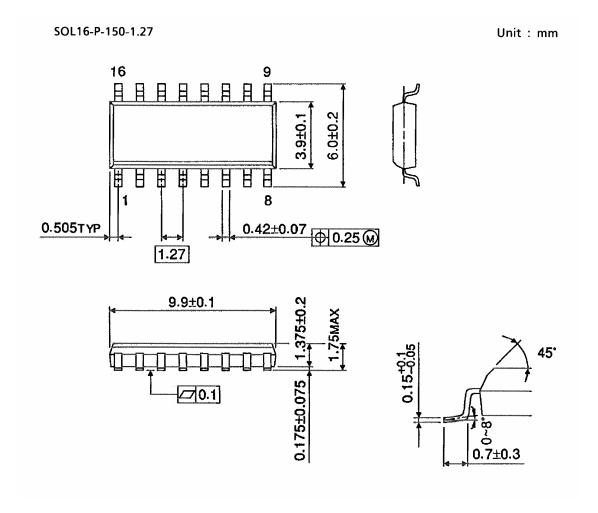
SOP16-P-300-1.27A Unit: mm



Weight: 0.18 g (typ.)



Package Dimensions (Note)

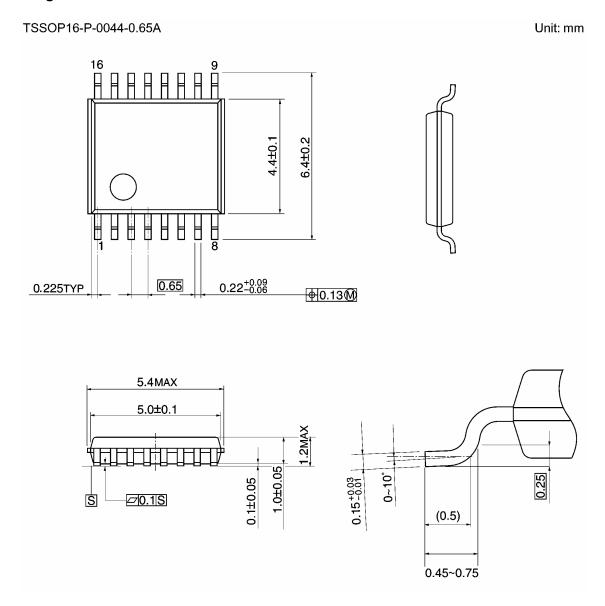


Note: This package is not available in Japan.

Weight: 0.13 g (typ.)



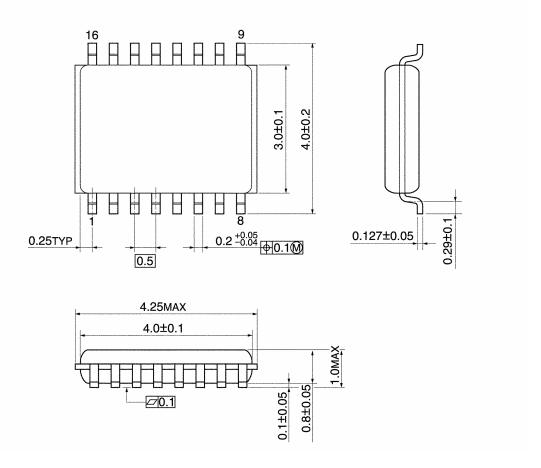
Package Dimensions



Weight: 0.06 g (typ.)

Package Dimensions

VSSOP16-P-0030-0.50 Unit: mm



Weight: 0.02 g (typ.)

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20070701-EN GENERAL

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